

Van der Waals stacked 2D layered materials for optoelectronics

2D Materials

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Citation Report

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2	2D Materials for Optical Modulation: Challenges and Opportunities. Advanced Materials, 2017, 29, 1606128.	11.1	364
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7	Recent Advances in Ultrathin Two-Dimensional Nanomaterials. Chemical Reviews, 2017, 117, 6225-6331.	23.0	3,940
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17	Temperature-Dependent Two-Dimensional Transition Metal Dichalcogenide Heterostructures: Controlled Synthesis and Their Properties. ACS Applied Materials & Interfaces, 2017, 9, 30821-30831.	4.0	47
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#	ARTICLE	IF	CITATIONS
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#	ARTICLE	IF	CITATIONS
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